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L. Spruill

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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: SHINYA SATOU ET AL.

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Serial No.: 09/936,480 Group Art Unit: 2855

Filed: DECEMBER 26, 2001 Examiner: MARISSA L. FERGUSON

Title: SEMICONDUCTOR PRESSURE SENSOR AND PRESSURE DETECTOR

REPLY UNDER 37 C.F.R. §1.111

Commissioner for Patents
Washington, D.C. 20231

Sir:

The following amendments and remarks are respectfully submitted in response to the Office Action dated October 2, 2002.

IN THE CLAIMS:

Please amend claims 1-9 as follows:

(A copy of the marked-up version of the amended claims are attached to this Reply).

1. (Amended) A semiconductor pressure sensor, comprising:
a substrate,
a diaphragm formed on said substrate by a sacrificial layer etching method, and

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